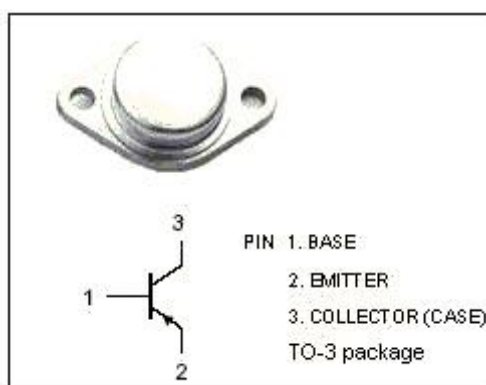


isc Silicon PNP Power Transistor
2SA757
DESCRIPTION

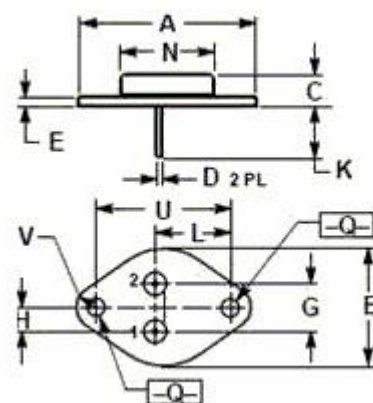
- High Power Dissipation-
: $P_C = 60W(\text{Max.})@T_C=25^\circ\text{C}$
- Collector-Emitter Breakdown Voltage-
: $V_{(BR)CEO} = -90V(\text{Min.})$
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

APPLICATIONS

- Designed for use in audio amplifier power output stage and general purpose applications.


ABSOLUTE MAXIMUM RATINGS($T_a=25^\circ\text{C}$)

SYMBOL	PARAMETER	VALUE	UNIT
V_{CBO}	Collector-Base Voltage	-120	V
V_{CEO}	Collector-Emitter Voltage	-90	V
V_{EBO}	Emitter-Base Voltage	-5	V
I_C	Collector Current-Continuous	-7	A
I_{CM}	Collector Current-Peak	-12	A
P_C	Collector Power Dissipation @ $T_C=25^\circ\text{C}$	60	W
T_j	Junction Temperature	150	$^\circ\text{C}$
T_{stg}	Storage Temperature	-55~150	$^\circ\text{C}$



DIM	mm	
	MIN	MAX
A	39.00	
B	25.30	26.67
C	7.80	8.50
D	0.90	1.10
E	1.40	1.60
G	10.92	
H	5.46	
K	11.30	13.50
L	16.75	17.05
N	19.40	19.62
Q	4.00	4.20
U	30.00	30.20
V	4.30	4.50

isc Silicon PNP Power Transistor**2SA757****ELECTRICAL CHARACTERISTICS**T_j=25°C unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT
V _{(BR)CEO}	Collector-Emitter Breakdown Voltage	I _C = -50mA; R _{BE} = ∞	-90			V
V _{(BR)CBO}	Collector-Base Breakdown Voltage	I _C = -5mA; I _E = 0	-120			V
V _{(BR)EBO}	Emitter-Base Breakdown Voltage	I _E = -5mA; I _C = 0	-5			V
V _{CE(sat)}	Collector-Emitter Saturation Voltage	I _C = -5A; I _B = -1A			-1.8	V
V _{BE(on)}	Base-Emitter On Voltage	I _C = -1A; V _{CE} = -5V			-1.5	V
I _{CBO}	Collector Cutoff Current	V _{CB} = -120V; I _E = 0			-1.0	mA
h _{FE-1}	DC Current Gain	I _C = -1A; V _{CE} = -5V	25		200	
h _{FE-2}	DC Current Gain	I _C = -5A; V _{CE} = -5V	20			
f _T	Current-Gain—Bandwidth Product	I _C = -1A; V _{CE} = -5V		24		MHz

◆ **h_{FE-1} Classifications**

A	B	C
25-60	50-120	100-200

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